## BDV65, BDV65A, BDV65B, BDV65C NPN SILICON POWER DARLINGTONS

# BOURNS®

- Designed for Complementary Use with BDV64, BDV64A, BDV64B and BDV64C
- 125 W at 25°C Case Temperature
- 12 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 1000 at 4 V, 5 A



Pin 2 is in electrical contact with the mounting base.



This model is currently available, but not recommended for new designs. For more information, see http://bourns.com/data/ global/pdfs/TSP1203\_S0T93\_P0M.pdf.

#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	BDV65		60		
Collector-base voltage ( $I_E = 0$ )	BDV65A	N/	80	v	
	BDV65B	V <sub>CBO</sub>	100	v	
	BDV65C		120		
Collector-emitter voltage ( $I_B = 0$ )	BDV65		60		
	BDV65A	N/	80	v	
	BDV65B	V <sub>CEO</sub>	100		
	BDV65C		120		
Emitter-base voltage			5	V	
Continuous collector current		Ι <sub>C</sub>	12	A	
Peak collector current (see Note 1)			15	A	
Continuous base current			0.5	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			125	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			3.5	W	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds			260	°C	

NOTES: 1. This value applies for  $t_p \leq 0.1$  ms, duty cycle  $\leq 10\%$ 

2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.

## PRODUCT INFORMATION

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#### electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER		TEST	CONDITIONS		MIN	ТҮР	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA	I <sub>B</sub> = 0	(see Note 4)	BDV65 BDV65A BDV65B BDV65C	60 80 100 120			V
I <sub>CEO</sub>	Collector-emitter cut-off current	$V_{CB} = 30 V$ $V_{CB} = 40 V$ $V_{CB} = 50 V$ $V_{CB} = 60 V$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		BDV65 BDV65A BDV65B BDV65C			2 2 2 2	mA
I <sub>CBO</sub>	Collector cut-off current	$V_{CB} = 120 V$ $V_{CB} = 30 V$ $V_{CB} = 40 V$ $V_{CB} = 50 V$	$I_{E} = 0$	$T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$	BDV65 BDV65A BDV65B BDV65C BDV65 BDV65A BDV65B BDV65C			0.4 0.4 0.4 2 2 2 2 2	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	$I_{\rm C} = 0$					5	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 4 V$	I <sub>C</sub> = 5 A	(see Notes 4 and	5)	1000			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> = 20 mA	I <sub>C</sub> = 5 A	(see Notes 4 and	5)			2	V
V <sub>BE</sub>	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 5 A	(see Notes 4 and	5)			2.5	V
V <sub>EC</sub>	Parallel diode forward voltage	I <sub>E</sub> = 10 A	I <sub>B</sub> = 0	(see Notes 4 and	5)			3.5	V

NOTES: 4. These parameters must be measured using pulse techniques,  $t_p = 300 \ \mu$ s, duty cycle  $\leq 2\%$ .

5. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### thermal characteristics

	PARAMETER		ТҮР	MAX	UNIT
R <sub>θJC</sub>	Junction to case thermal resistance			1	°C/W
R <sub>θJA</sub>	Junction to free air thermal resistance			35.7	°C/W



### **TYPICAL CHARACTERISTICS**



**BASE-EMITTER SATURATION VOLTAGE** vs **COLLECTOR CURRENT** TCS140AF 3.0  $T_c = -40^{\circ}C$ V<sub>BE(sat)</sub> - Base-Emitter Saturation Voltage - V  $T_c = 25^{\circ}C$ 2.5 100°C T<sub>c</sub> = 2.0 1.5 1.0 0.5 = I<sub>c</sub> / 100 I<sub>B</sub> = 300  $\mu$ s, duty cycle < 2% t, 111 0 0.5 1.0 10 20 I<sub>c</sub> - Collector Current - A Figure 3.



JUNE 1993 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.

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## THERMAL INFORMATION





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Authorized Distributor

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